



TELEFUNKEN electronic
Creative Technologies

BF 885 S

T-33-05

Silicon NPN Epitaxial Planar RF Transistor

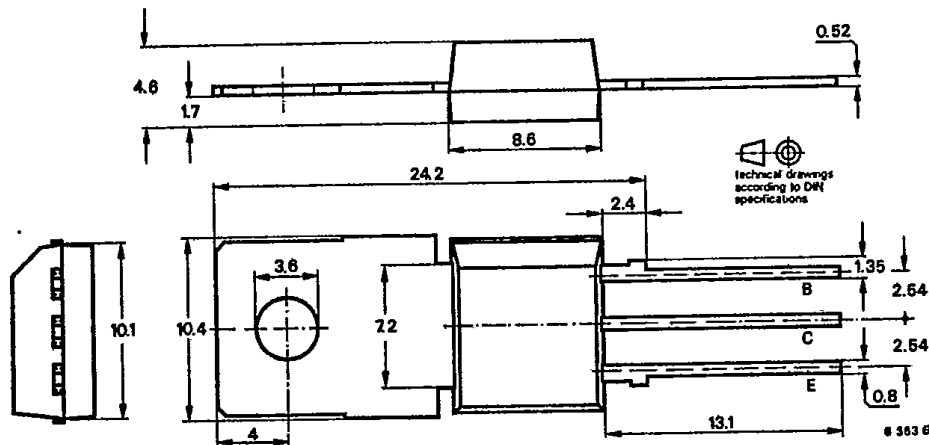
Applications: Video B-class power stages in TV receivers

Features:

● High reverse voltage

● No h_{FE} -drift dependent of temperature

Dimensions in mm



Standard plastic case

34 A 3 DIN 41 869

JEDEC TO 202

Weight max. 1.8 g

Collector connected with metallic surface

Absolute maximum ratings

Collector-base voltage	V_{CBO}	300	V
Collector-emitter voltage	V_{CER}	300	V
$R_{BE} \leq 2.7 \text{ k}\Omega$	V_{EBO}	5	V
Emitter-base voltage	I_C	50	mA
Collector current	I_{CM}	300	mA
Collector peak current	P_{tot}	7	W
Total power dissipation	T_J	150	°C
$T_{case} \leq 25 \text{ °C}$	T_{stg}	-65 ... +150	°C
Junction temperature			
Storage temperature range			

Maximum thermal resistances

Junction ambient	R_{thJA}	78	K/W
Junction case	R_{thJC}	178	K/W

T1.2/821.0888 E

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Characteristics

Min. Typ. Max.

 $T_{amb} = 25^{\circ}C$, unless otherwise specified

Collector cut-off current

 $V_{CE} = 250 V, R_{BE} = 2.7 k\Omega$ I_{CER}

50 nA

 $V_{CE} = 200 V, R_{BE} = 2.7 k\Omega, T_J = 150^{\circ}C$ I_{CER} 10 μA

Emitter cut-off current

 $V_{EB} = 5 V$ I_{EBO} 10 μA

Collector-emitter breakdown voltage

 $I_C = 1 \mu A, R_{BE} = 2.7 k\Omega$ $V_{(BR)CER}$

300

V

DC forward current transfer ratio

 $V_{CE} = 20 V, I_C = 25 mA$ h_{FE}

50

Gain bandwidth product

 $V_{CE} = 10 V, I_C = 10 mA$ f_T

60

90

MHz

Feedback capacitance

 $V_{CE} = 30 V, I_C = 1 mA, f = 1 MHz$ $C_{12\phi}$

1.2

1.8

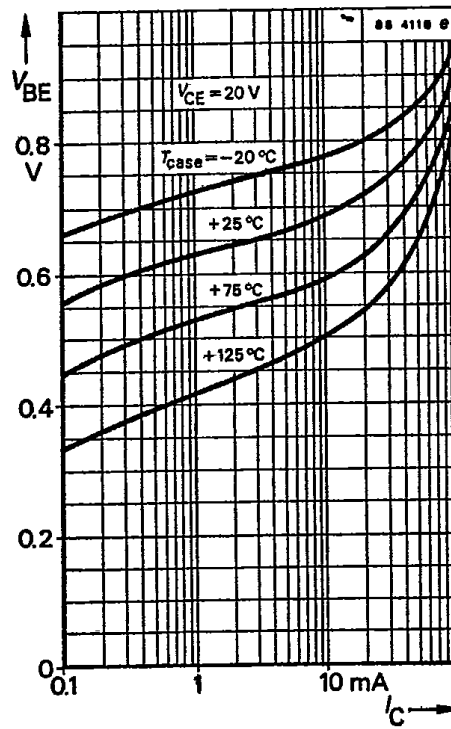
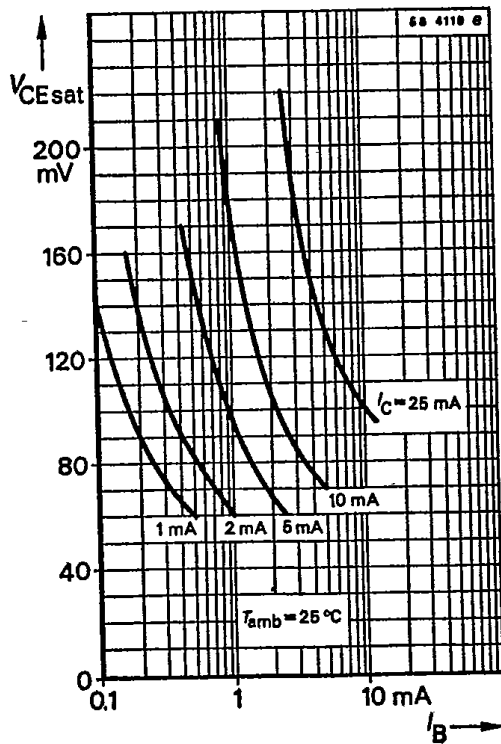
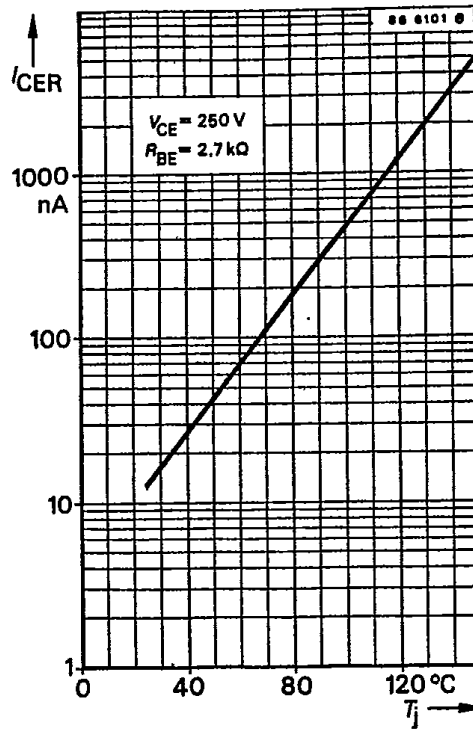
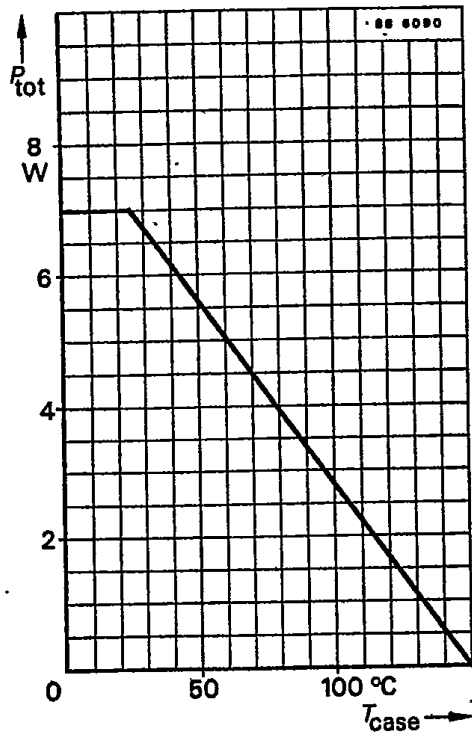
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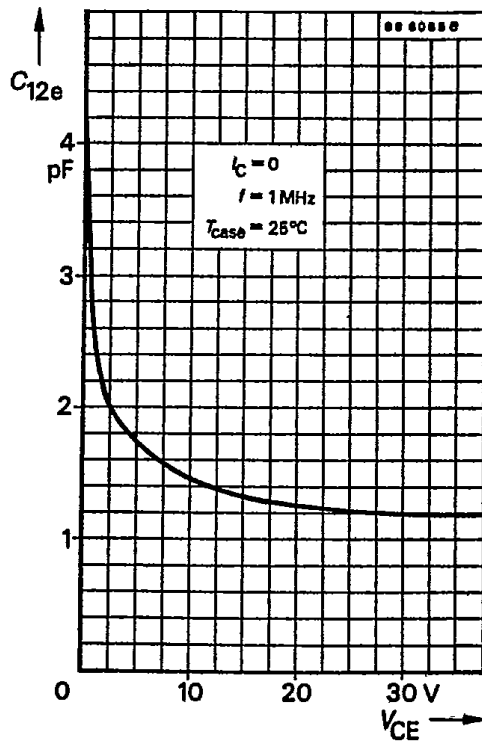
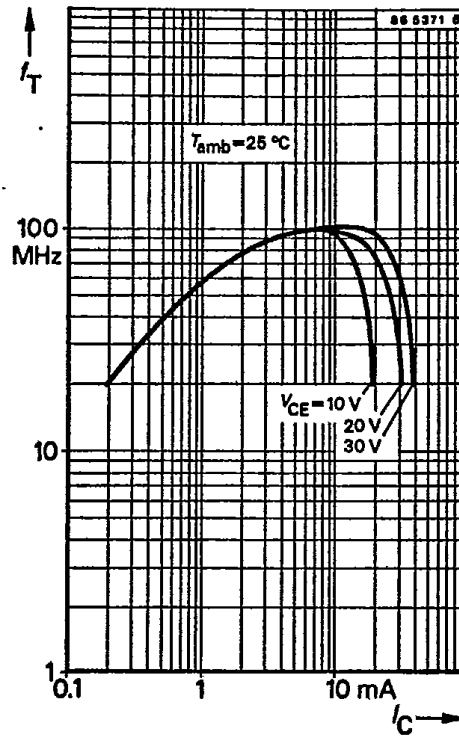
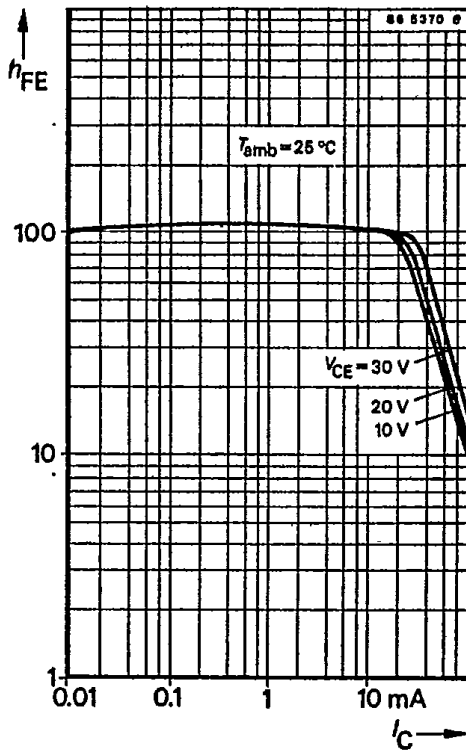
Collector saturation RF voltage

 $I_C = 25 mA, T_J = 150^{\circ}C$ $V_{CEsatHF}$

20

V





- **Family of curves**

Besides the static (d. c.) and dynamic (a. c.) characteristics, family of curves are given for specified operating conditions. They show the typical interdependence of individual characteristics. Partly are given the scattering limits. They signify that at least 95% of the delivery lies inside these tolerances.

6.6. Additional informations

Preliminary specifications

This heading indicates that some information on the device concerned may be subject to slight changes.

Not for new developments

This heading indicates that the device concerned should not be used in equipment under development, it is, however, available for present production.

7. Taping and reeling

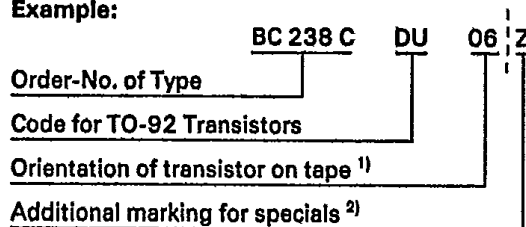
7.1. Taping of TO-92 transistors

Standard reeling: Taped on reel, reeled together with a paper film.

7.1.1. Order Numbers

Add the taping-code to the order number.

Example:



¹⁾ 06 = View on flat side of transistor, view on gummed tape

05 = View on round side of transistor, view on gummed tape

2) Additional marking "0" :

Taping without paper film

Additional marking "Z":

Zigzag folded tape in special box. Marking for orientation of transistor not necessary, because box can be opened on top or bottom.

Example for order No.: BC 237 C DU Z

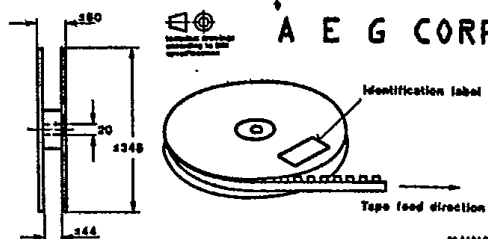


Fig. 7.1. Dimensions of reel in mm

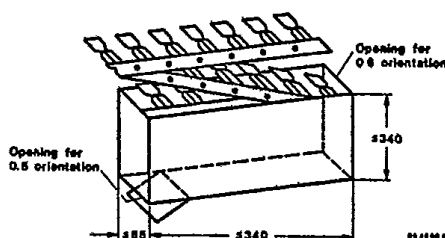


Fig. 7.2. Dimension of box for Zigzag folding in mm

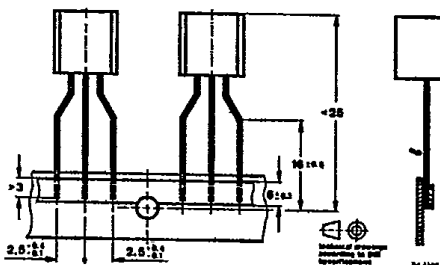


Fig. 7.3. Dimensions of tape in mm

7.1.2 Quantity of devices

1 000 devices per reel

2000 devices per folded tape in special box.

7.2 Taped transistors in SOT 23 and SOT 143 case

a) Standard taping

Designation is attached with code GS 08 in case of standard taping. Example for normal version transistors as standard taped: BF 569-GS08.

Example for R-version transistors as standard taped: BF 569 R-GS 08.

In case of standard taping, the transistor orientation on the tape is shown in Fig. 7.4 and Fig. 7.5.

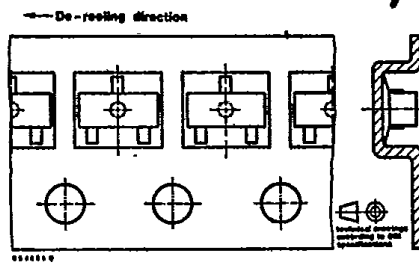


Fig. 7.6 Reverse taped SOT 23

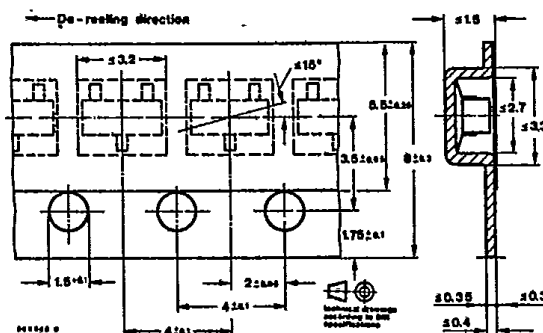


Fig. 7.7 Dimensions of tape in mm

[illegible]

7.2.2 Quantity of devices
3000 devices per reel

For case

Number	Fig.	Designation	For case
119880	8.1.	Isolating washer thickness 60 µm	12A 3 DIN 41 869 JEDEC TO 126 (SOT 32)
564542	8.2.	Isolating washer thickness 50 µm	14A 3 DIN 41 869 JEDEC TO 220 (SOT 78)
912884	8.3	Isolating washer thickness 50 µm	15A 3 DIN 41 869 (TOP3) for clip mounting
191131	8.4	Isolating washer thickness 50 µm	15A 3 DIN 41 869 (TOP3) for screw mounting
191140	8.5	Mounting clip	15A 3 DIN 41 869 (TOP3)
569524	8.6	Isolating washer thickness 100 µm + 50 µm	3B 2 DIN 41 872 JEDEC TO 3 Devices with high reverse voltage